SN5475, SN5477, SN54LS75, SN54LS77 SN7475, SN74LS75 4-BIT BISTABLE LATCHES SDLS120 – MARCH 1974 – REVISED MARCH 1988

FUNCTION TABLE (each latch)

INP	UTS	ουτι	PUTS
D	С	٩	ā
L	Н	L	н
н	н	н	L
x	L	Q ₀	ā ₀

H = high level, L = low level, X = irrelevant

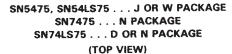
 Q_0 = the level of Q before the high-to-low transition of G

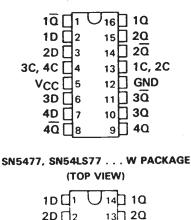
description

These latches are ideally suited for use as temporary storage for binary information between processing units and input/output or indicator units. Information present at a data (D) input is transferred to the Q output when the enable (C) is high and the Q output will follow the data input as long as the enable remains high. When the enable goes low, the information (that was present at the data input at the time the transition occurred) is retained at the Q output until the enable is permitted to go high.

The '75 and 'LS75 feature complementary Q and \overline{Q} outputs from a 4-bit latch, and are available in various 16-pin packages. For higher component density applications, the '77 and 'LS77 4-bit latches are available in 14-pin flat packages.

These circuits are completely compatible with all popular TTL families. All inputs are diode-clamped to minimize transmission-line effects and simplify system design. Series 54 and 54LS devices are characterized for operation over the full military temperature range of -55 °C to 125 °C; Series 74, and 74LS devices are characterized for operation from 0°C to 70 °C.

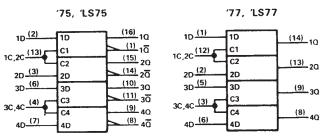




2D 🗋 2	13 20
3C, 4C 🖾 3	12 1C, 2C
Vcc ⊡₄	
3D 🗍 5	10 NC
4D ☐6	9 0 30
	8 40

NC - No internal connection

logic symbols[†]



[†]These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC (See Note 1)		7 V
Interemitter voltage (see Note 2)		5.5 V
Operating free-air temperature range:	SN54'	-55°C to 125°C
	SN74'	0° C to 70°C
Storage temperature range		-65°C to 150°C

NOTES: 1. Voltage values are with respect to network ground terminal.

2. This is the voltage between two emitters of a multiple-emitter input transistor and is not applicable to the 'LS75 and 'LS77.

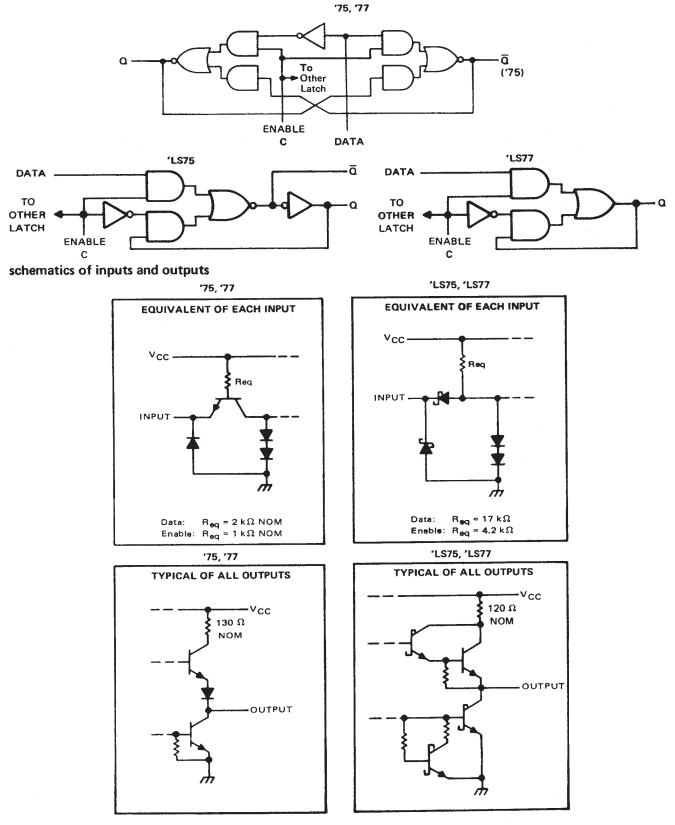
PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



SN5475, SN5477, SN54LS75, SN54LS77 SN7475, SN74LS75 4-BIT BISTABLE LATCHES

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logic diagrams (each latch) (positive logic)





recommended operating conditions

	SN54	475, SN	5477	SN7475			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	UNT
Supply voltage, V _{CC}	4.5	5	5.5	4.75	5	5,25	V
High-level output current, IOH			-400			-400	μA
Low-level output current, IOL			16			16	mA
Width of enabling pulse, t _W	20			20			ns
Setup time, t _{su}	20			20			ns
Hold time, t _h	5			5			ns
Operating free-air temperature, TA	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER		TEST CO	DITIONS	MIN	TYP‡	MAX	UNIT
VIH	High-level input voltage				2			V
VIL	Low-level input voltage				1		0.8	V
VIK	Input clamp voltage	· · · · · · · · · · · · · · · · · · ·	V _{CC} = MIN,	l _l = -12 mA			-1.5	V
V _{OH}	High-level output voltage		V _{CC} = MIN, V _{IL} = 0.8 V,	V _{1H} = 2 V, I _{OH} = -400 μA	2.4	3.4		v
VOL	Low-level output voltage		V _{CC} = MIN, V _{IL} = 0.8 V,	V _{IH} = 2 V, I _{OL} = 16 mA		0.2	0.4	v
4	Input current at maximum input voltage		V _{CC} = MAX,	V ₁ = 5.5 V			1	mA
ŧн	High-level input current	D input C input	V _{CC} = MAX,	V _I = 2.4 V			80 160	μA
		D input					-3.2	
ηL	Low-level input current	C input	V _{CC} = MAX,	V1 = 0.4 V			-6.4	mA
				SN54'	-20		-57	
los	Short-circuit output current §		V _{CC} = MAX	SN74'	-18		-57	mA
	Current and the second se		V _{CC} = MAX,	SN54'		32	46	mA
1CC	Supply current		See Note 3	SN74'		32	53	

[†]For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

[‡]All typical values are at $V_{CC} = 5 V$, $T_A = 25^{\circ}C$.

[§]Not more than one output should be shorted at a time.

NOTE 3: ICC is tested with all inputs grounded and all outputs open.

switching characteristics, $V_{CC} = 5 V$, $T_A = 25^{\circ}C$

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	ТҮР	MAX	UNIT
tPLH					16	30	
^t PHL	D	Q			14	25	ns
t₽LH¶	D	ā	0 15 p5		24	40	ns
tPHL¶	U	ŭ	C _L = 15 pF, - R _L = 400 Ω,		7	15	
^t PLH	С	Q	See Figure 1		16	30	ns
^t PHL	C	ŭ	See a igure i		7	15] ""
tPLH¶	С	ā	1		16	30	ns
tPHL¶	U U	u u			7	15]

 $t_{PLH} \equiv$ propagation delay time, low-to-high-level output $t_{PHL} \equiv$ propagation delay time, high-to-low-level output

These parameters are not applicable for the SN5477.



SN5475, SN5477, SN54LS75, SN54LS77 SN7475, SN74LS75 4-BIT BISTABLE LATCHES

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recommended operating conditions

· · · · · · · · · · · · · · · · · · ·		N54LS7 N54LS7		SN74LS75			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
Supply voltage, V _{CC}	4.5	5	5.5	4.75	5	5.25	V
High-level output current, IOH			-400			-400	μA
Low-level output current, IOL			4			8	mA
Width of enabling pulse, tw	20			20			ns
Setup time, t _{su}	20			20			ns
Hold time, th	5			5			ns
Operating free-air temperature, TA	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS [†]				N54LS7 N54LS7		s	N74LS7	75	UNIT
						TYP‡	MAX	MIN	TYP [‡]	MAX	
VIH	High-level input voltage				2			2			V
VIL	Low-level input voltage						0.7			0.8	V
VIK	Input clamp voltage	V _{CC} = MIN,	l _l = -18 mA				-1.5			-1.5	V
VOH	High-level output voltage	$V_{CC} = MIN,$ $V_{1L} = V_{1L} max,$		۱A	2.5	3.5		2.7	3.5		v
		V _{CC} = MIN,	VIH = 2 V,	10L = 4 mA		0.25	0.4		0.25	0.4	
VOL	Low-level output voltage	VIL = VIL max		IOL = 8 mA					0.35	0.5	
	Input current at)/ _ 7)/	D input			0.1			0.1	- mA
4	maximum input voltage	V _{CC} = MAX,	V1 = 7 V	C input			0.4			0.4	
				D input			20			20	μA
ЧН	High-level input current	V _{CC} = MAX,	V1 = 2.7 V	C input			80			80	
				D input			-0.4			-0.4	mA
ΠL	Low-level input current	V _{CC} = MAX,	V _I = 0.4 V	C input			-1.6			-1.6	1
los	Short-circuit output current §	V _{CC} = MAX			-20		-100	20		-100	mA
			See Note 2	'LS75		6.3	12		6.3	12	mA
lcc	Supply current	V _{CC} = MAX,	See Note 2	'LS77	T	6.9	13				

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

[‡]All typical values are at $V_{CC} = 5 V$, $T_A = 25^{\circ}C$.

Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second NOTE 2: ICC is tested with all inputs grounded and all outputs open.

switching characteristics, $V_{CC} = 5 V$, $T_A = 25^{\circ}C$

	FROM	то		Τ	'LS75			'LS77		UNIT
PARAMETER¶	(INPUT)	(OUTPUT)	T) TEST CONDITIONS		ТҮР	MAX	MIN	түр	MAX	
^t PLH					15	27		11	19	ns
tPHL	D	Q			9	17		9	17	113
<u>тргн</u>					12	20				ns
tPHL	D	ā	C _L = 15 pF,		7	15				
tPLH			R _L = 2 kΩ,		15	27		10	18	ns
tPHL	с	Q	See Figure 1		14	25		10	18	
tPLH		-			16	30	1			ns
TPHL	с	ā			7	15				

¶ tpLH = propagation delay time, low-to-high-level output

tpLH = propagation delay time, high-to-low-level output



switching characteristics[†] INPUTS OUTPUTS v_{cc} ā D С a RL PULSE D Q GENERATOR (See Note A) (See Note C) = 15 pF Cı С (See Note B) ā PULSE GENERATOR B $C_L = 15 \, pF$ (See Note A) (See Note B) TEST CIRCUIT 1 µs μs < 10 ns < 10 ns 3 V 90% 90% V_{ref} Vref D INPUT V_{ref} 10% 10% tsu 0 V h t_{su} < 10 ns th 10 ns 3 V 90% 90% C INPUT (See Vref ref Vref Vref 10% 10% Note D) 0 V 500 ns 500 ns ^tPLH TPHL tPH1 VOH Vref OUTPUT Q Vref VOL TPLH - Vон ^tPLH Vref Vref OUTPUT Q tPH VOL - TPHL

PARAMETER MEASUREMENT INFORMATION

VOLTAGE WAVEFORMS

[†]Complementary Q outputs are on the '75 and 'LS75 only.

- NOTES: A. The pulse generators have the following characteristics: Z_{out} ≈ 50 Ω; for pulse generator A, PRR ≤ 500 kHz; for pulse generator B, PRR ≤ 1 MHz. Positions of D and C input pulses are varied with respect to each other to verify setup times.
 B. C_L includes probe and jig capacitance.
 - C. All diodes are 1N3064 or equivalent.
 - D. When measuring propagation delay times from the D input, the corresponding C input must be held high.
 - E. For '75 and '77, $V_{ref} = 1.5 V$; for 'LS75 and 'LS77, $V_{ref} = 1.3 V$.

FIGURE 1





Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*A	l dimensions are nominal												
ſ	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	SN74LS75DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
	SN74LS75NSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1

Pack Materials-Page 1



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PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LS75DR	SOIC	D	16	2500	340.5	336.1	32.0
SN74LS75NSR	SO	NS	16	2000	356.0	356.0	35.0

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TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
7601201FA	W	CFP	16	1	506.98	26.16	6220	NA
SN74LS75D	D	SOIC	16	40	507	8	3940	4.32
SN74LS75N	N	PDIP	16	25	506	13.97	11230	4.32
SN74LS75N	N	PDIP	16	25	506	13.97	11230	4.32
SNJ54LS75W	W	CFP	16	1	506.98	26.16	6220	NA

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